

## DUAL OPERATIONAL AMPLIFIER

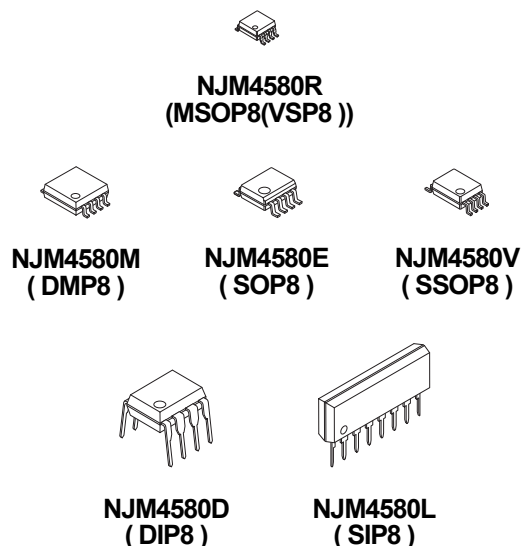
### ■ GENERAL DESCRIPTION

The NJM4580 is a dual operational amplifier, specially designed for improving the tone control, which is most suitable for the audio application.

Featuring noiseless, higher gain bandwidth, high output current and low distortion ratio, and it is most suitable not only for acoustic electronic parts of audio pre-amp and active filter, but also for the industrial measurement tools. It is also suitable for the head phone amp at higher output current, and further more, it can be applied for the handy type set operational amplifier of general purpose in application of low voltage single supply type which is properly biased of the low voltage source.

The D-Rank type products(NJM4580DD/LD/MD/ED) have specified maximum limits for equivalent input noise voltage.

### ■ PACKAGE OUTLINE

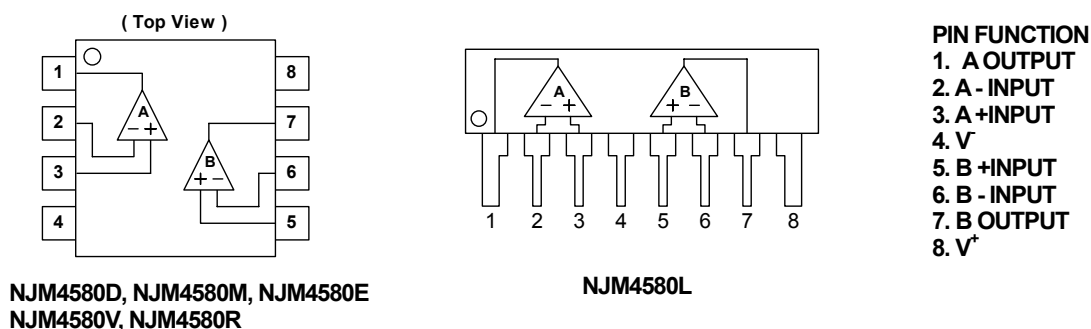


### ■ FEATURES

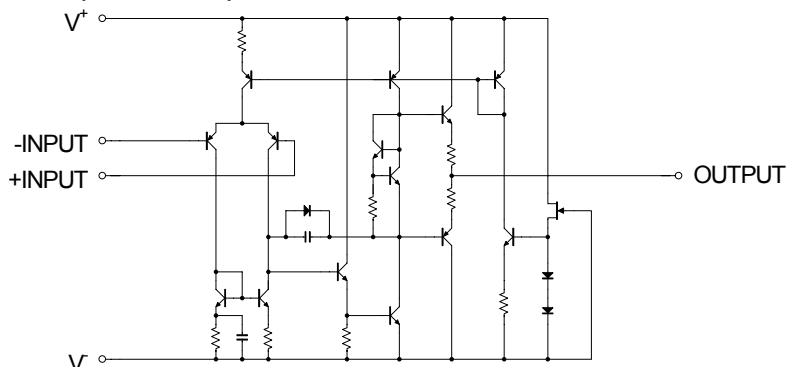
- Operating Voltage  $\pm 2V \sim \pm 18V$
- Low Input Noise Voltage  $0.8\mu V_{rms}$  typ. (RIAA)
- Wide GBW  $15MHz$  typ.
- Low Distortion  $0.0005\%$  typ.
- Slew Rate  $5V/\mu s$  typ.
- Bipolar Technology
- Package Outline

DIP8, SIP8, DMP8, SSOP8, MSOP8(VSP8) MEET JEDEC MO-187-DA  
SOP8 JEDEC 150mil

### ■ PIN CONFIGURATION



### ■ EQUIVALENT CIRCUIT ( 1/2 Shown )



# NJM4580

## ■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C, unless otherwise noted.)

| PARAMETER                   | SYMBOL      | RATING                                                                           | UNIT |
|-----------------------------|-------------|----------------------------------------------------------------------------------|------|
| Supply Voltage              | $V^+ / V^-$ | ±18                                                                              | V    |
| Input Voltage               | $V_{ICM}$   | ±15 (Note1)                                                                      | V    |
| Differential Input Voltage  | $V_{ID}$    | ±30 (Note1)                                                                      | V    |
| Power Dissipation           | $P_D$       | DIP8, SIP8 : 800<br>DMP8, SOP8 : 300<br>SSOP8 : 250<br>MSOP8(VSP8) : 400 (Note2) | mW   |
| Operating Temperature Range | Topr        | -40~+85                                                                          | °C   |
| Storage Temperature Range   | Tstg        | -40~+125                                                                         | °C   |

(Note1) For supply voltage less than ±15V, the absolute maximum input voltage is equal to supply voltage.

(Note2) On the PCB "EIA/JEDEC (114.3×76.2×1.57mm, 2 layers, FR-4)"

## ■ RECOMMENDED OPERATING CONDITIONS

(Ta=25°C)

| PARAMETER      | SYMBOL      | CONDITION | MIN. | TYP. | MAX. | UNIT |
|----------------|-------------|-----------|------|------|------|------|
| Supply Voltage | $V^+ / V^-$ |           | ±2   | -    | ±18  | V    |

## ■ ELECTRICAL CHARACTERISTICS

( $V^+ / V^- = \pm 15V$ , Ta=25°C, unless otherwise noted.)

| PARAMETER                       | SYMBOL    | TEST CONDITION                                   | MIN. | TYP.   | MAX. | UNIT  |
|---------------------------------|-----------|--------------------------------------------------|------|--------|------|-------|
| Input Offset Voltage            | $V_{IO}$  | $R_S \leq 10k\Omega$                             | -    | 0.3    | 3    | mV    |
| Input Offset Current            | $I_{IO}$  |                                                  | -    | 5      | 200  | nA    |
| Input Bias Current              | $I_B$     |                                                  | -    | 100    | 500  | nA    |
| Voltage Gain                    | $A_V$     | $R_L \geq 2k\Omega, V_O = \pm 10V$               | 90   | 110    | -    | dB    |
| Maximum Output Voltage          | $V_{OM}$  | $R_L \geq 2k\Omega$                              | ±12  | ±13.5  | -    | V     |
| Common Mode Input Voltage Range | $V_{ICM}$ |                                                  | ±12  | ±13.5  | -    | V     |
| Common Mode Rejection Ratio     | CMR       | $R_S \leq 10k\Omega$                             | 80   | 110    | -    | dB    |
| Supply Voltage Rejection Ratio  | SVR       | $R_S \leq 10k\Omega$                             | 80   | 110    | -    | dB    |
| Supply Current                  | $I_{CC}$  |                                                  | -    | 6      | 9    | mA    |
| Slew Rate                       | SR        | $R_L \geq 2k\Omega$                              | -    | 5      | -    | V/μs  |
| Gain Bandwidth Product          | GB        | $f = 10kHz$                                      | -    | 15     | -    | MHz   |
| Total Harmonic Distortion       | THD       | $A_V = 20dB, V_O = 5V, R_L = 2k\Omega, f = 1kHz$ | -    | 0.0005 | -    | %     |
| Equivalent Input Noise Voltage  | $V_{NI}$  | RIAA, $R_S = 2.2k\Omega, 30kHz$ LPF              | -    | 0.8    | -    | μVrms |

## ■ ELECTRICAL CHARACTERISTICS

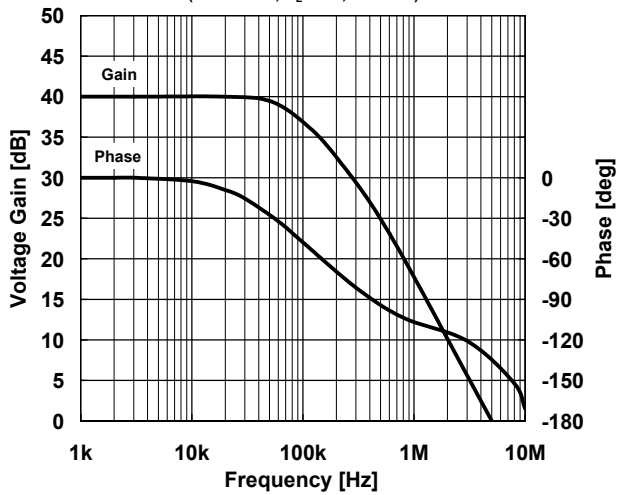
(D-rank type(Note3),  $V^+ / V^- = \pm 15V$ , Ta=25°C, unless otherwise noted.)

| PARAMETER                      | SYMBOL   | TEST CONDITION           | MIN. | TYP. | MAX. | UNIT  |
|--------------------------------|----------|--------------------------|------|------|------|-------|
| Equivalent Input Noise Voltage | $V_{NI}$ | RIAA, $R_S = 2.2k\Omega$ | -    | -    | 1.4  | μVrms |

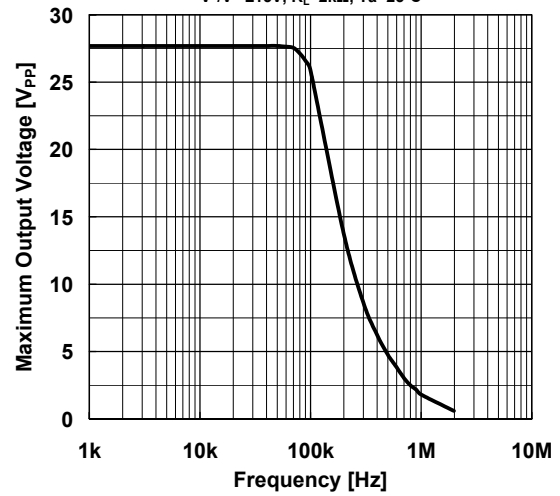
(Note3) D-rank type is a Equivalent Input Noise Voltage selected product. It s only DIP, DMP, SOP and SIP package.

## ■ TYPICAL CHARACTERISTICS

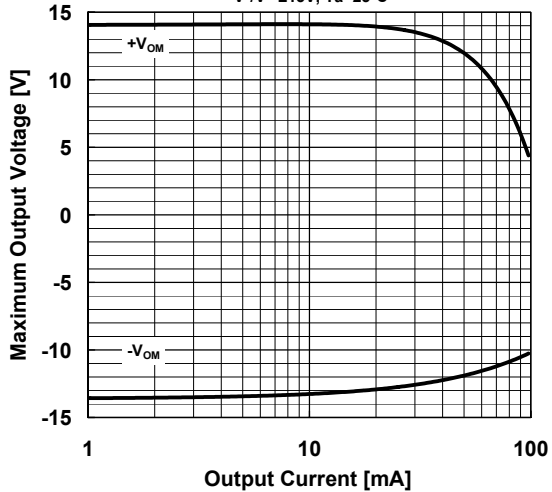
40dB Gain/Phase vs. Frequency  
( $V^+/V^-=\pm 15V$ ,  $R_L=2k\Omega$ ,  $T_a=25^\circ C$ )



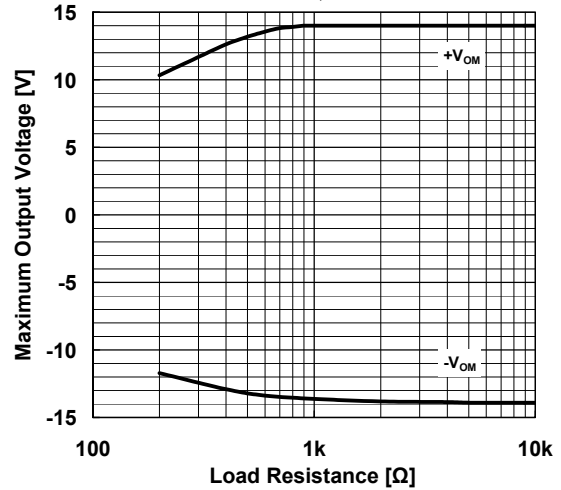
Maximum Output Voltage vs. Frequency  
 $V^+/V^-=\pm 15V$ ,  $R_L=2k\Omega$ ,  $T_a=25^\circ C$



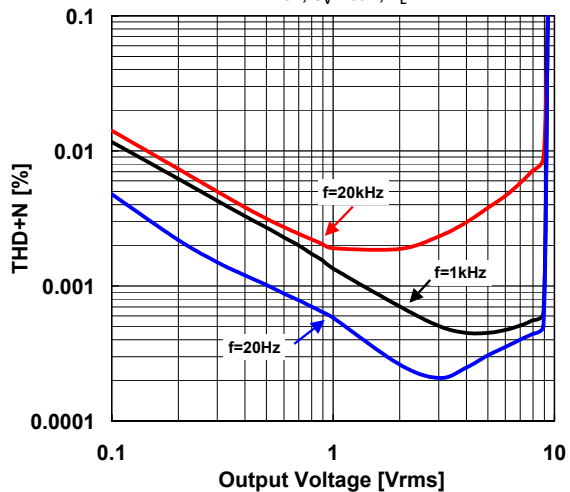
Maximum Output Voltage vs. Output Current  
 $V^+/V^-=\pm 15V$ ,  $T_a=25^\circ C$



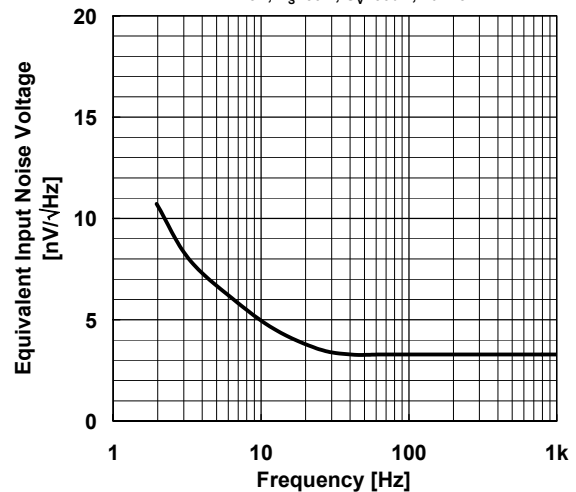
Maximum Output Voltage vs. Load Resistance  
 $V^+/V^-=\pm 15V$ ,  $T_a=25^\circ C$



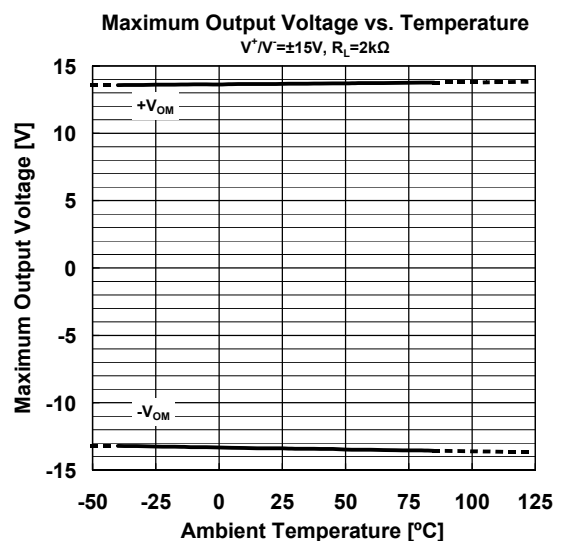
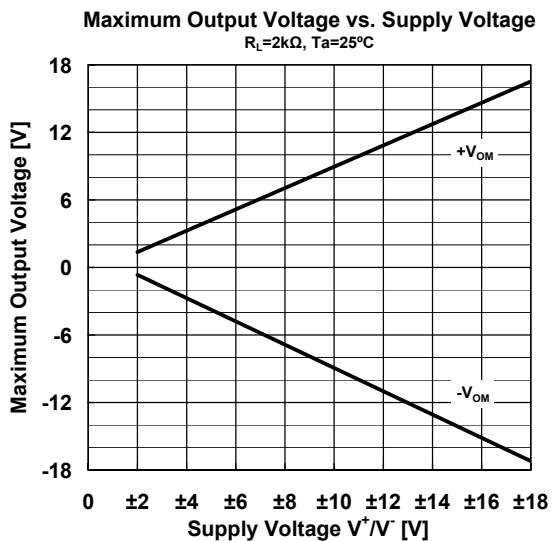
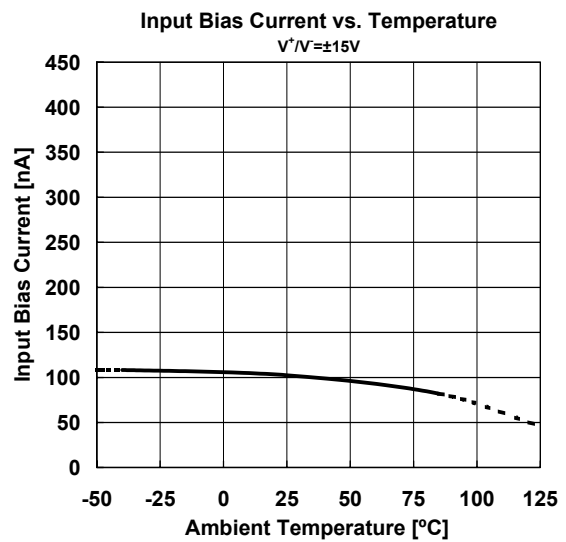
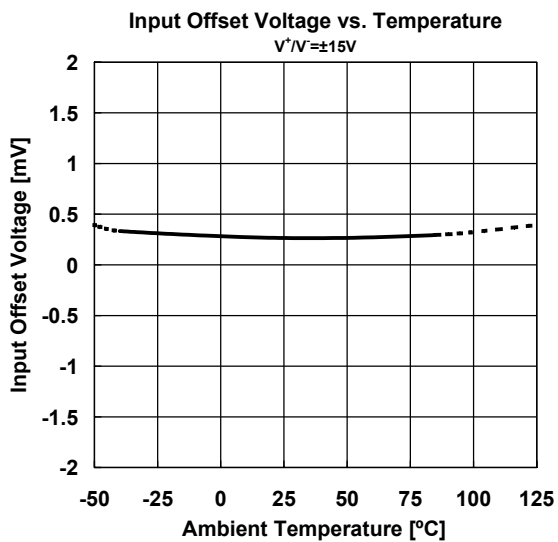
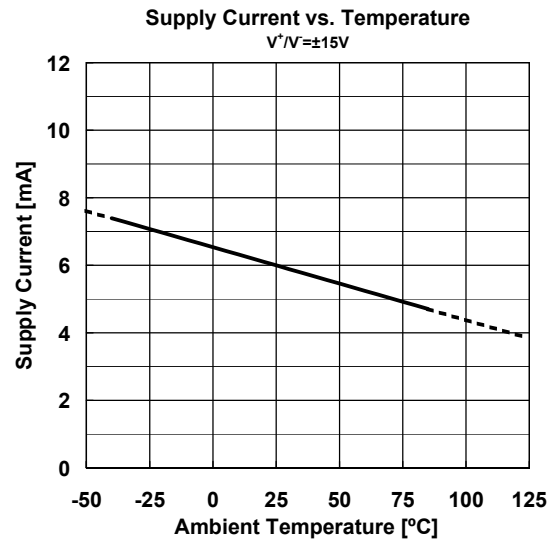
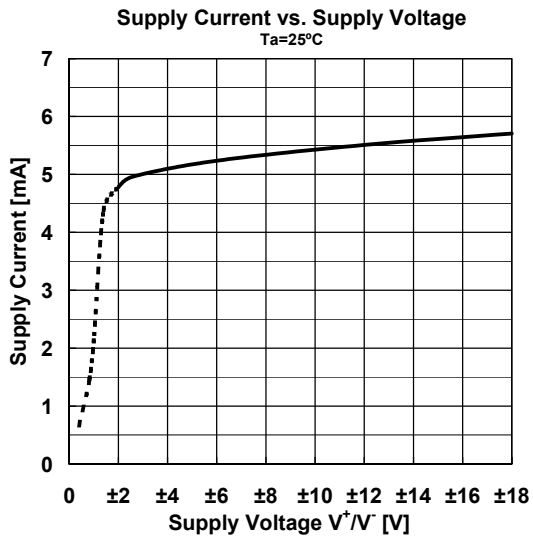
THD+N vs. Output Voltage (Frequency)  
 $V^+/V^-=\pm 15V$ ,  $G_v=20dB$ ,  $R_L=2k\Omega$



Voltage Noise vs. Frequency  
 $V^+/V^-=\pm 15V$ ,  $R_s=50\Omega$ ,  $G_v=60dB$ ,  $T_a=25^\circ C$

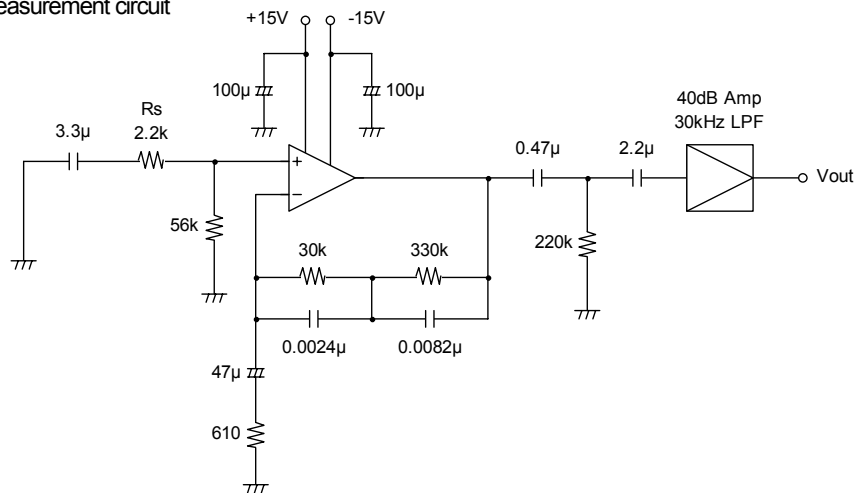


## ■ TYPICAL CHARACTERISTICS



## ■ TEST CIRCUIT

Noise Voltage (RIAA) measurement circuit



**[CAUTION]**

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